



Pages 1 to 18

TRANSISTORS, HIGH POWER, NPN

BASED ON TYPE 2N5154

ESCC Detail Specification No. 5203/010

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DCR No.	CHANGE DESCRIPTION
429, 447, 486	Specification up issued to incorporate editorial and technical changes per DCRs.

TABLE OF CONTENTS

1.	<u>GENERAL</u>	5
1.1	Scope	5
1.2	Applicable Documents	5
1.3	Terms, Definitions, Abbreviations, Symbols and Units	5
1.4	The ESCC Component Number and Component Type Variants	5
1.4.1	The ESCC Component Number	5
1.4.2	Component Type Variants	5
1.5	Maximum Ratings	6
1.6	Handling Precautions	7
1.7	Physical Dimensions and Terminal Identification	8
1.7.1	Metal Can Package (TO-39) - 3 lead	8
1.7.2	Metal Flange Mount Package (TO-257) - 3 lead	9
1.7.3	Surface Mount Package (SMD.5) - 3 terminal	10
1.8	Functional Diagram	11
1.9	Materials and Finishes	11
2.	<u>REQUIREMENTS</u>	12
2.1	General	12
2.1.1	Deviations from the Generic Specification	12
2.1.1.1	Deviation from Screening Tests - Chart F3	12
2.1.1.2	Deviation from Qualification and Periodic Tests - Chart F4	12
2.2	Marking	12
2.3	Terminal Strength	12
2.4	Verification of Safe Operating Area	13
2.5	Electrical Measurements at Room, High and Low Temperatures	13
2.5.1	Room Temperature Electrical Measurements	13
2.5.2	High and Low Temperatures Electrical Measurements	15
2.6	Parameter Drift Values	16
2.7	Intermediate and End-Point Electrical Measurements	16
2.8	Power Burn-in Conditions	17
2.8.1	Power Burn-in Conditions (TO-39)	17
2.8.2	Power Burn-in Conditions (TO-257 and SMD.5)	17
2.9	Operating Life Conditions	17
APPENDIX 'A'		18

1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 The ESCC Component Number

The ESCC Component Number shall be constituted as follows:

Example: 520301001

- Detail Specification Reference: 5203010
- Component Type Variant Number: 01 (as required)

1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Lead/Terminal Material and Finish	Weight max g
01	2N5154	TO-39	D2	1.5
02	2N5154	TO-39	D3 or D4	1.5
03	2N5154	TO-39	D7	1.5
04	2N5154	TO-257	H2	5
05	2N5154	TO-257	H4	5
06	2N5154	SMD.5	Q14	2
07	2N5154	SMD.5	Q14	2

The lead/terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

1.5 **MAXIMUM RATINGS**

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Collector-Base Voltage	V_{CBO}	100	V	Over T_{op}
Collector-Emitter Voltage	V_{CEO}	80	V	Over T_{op} Note 5
Emitter-Base Voltage	V_{EBO}	6	V	Over T_{op}
Collector Current	I_C	5	A	Continuous Note 5
Base Current	I_B	1	A	Continuous
Power Dissipation For TO-39 For TO-257 and SMD.5	P_{tot1}	1 3.3	W	At $T_{amb} \leq +25^{\circ}C$ Note 1
For TO-39 For TO-257 and SMD.5	P_{tot2}	8.75 35	W	At $T_{case} \leq +25^{\circ}C$ Note 1
Thermal Resistance, Junction-to-Ambient For TO-39 For TO-257 and SMD.5	$R_{th(j-a)}$	175 53	$^{\circ}C/W$	
Thermal Resistance, Junction-to-Case For TO-39 For TO-257 and SMD.5	$R_{th(j-c)}$	20 5	$^{\circ}C/W$	
Operating Temperature Range	T_{op}	-65 to +200	$^{\circ}C$	Note 2
Storage Temperature Range	T_{stg}	-65 to +200	$^{\circ}C$	Note 2
Soldering Temperature For TO-39 and TO-257 For SMD.5	T_{sol}	+260 +245	$^{\circ}C$	Note 3 Note 4

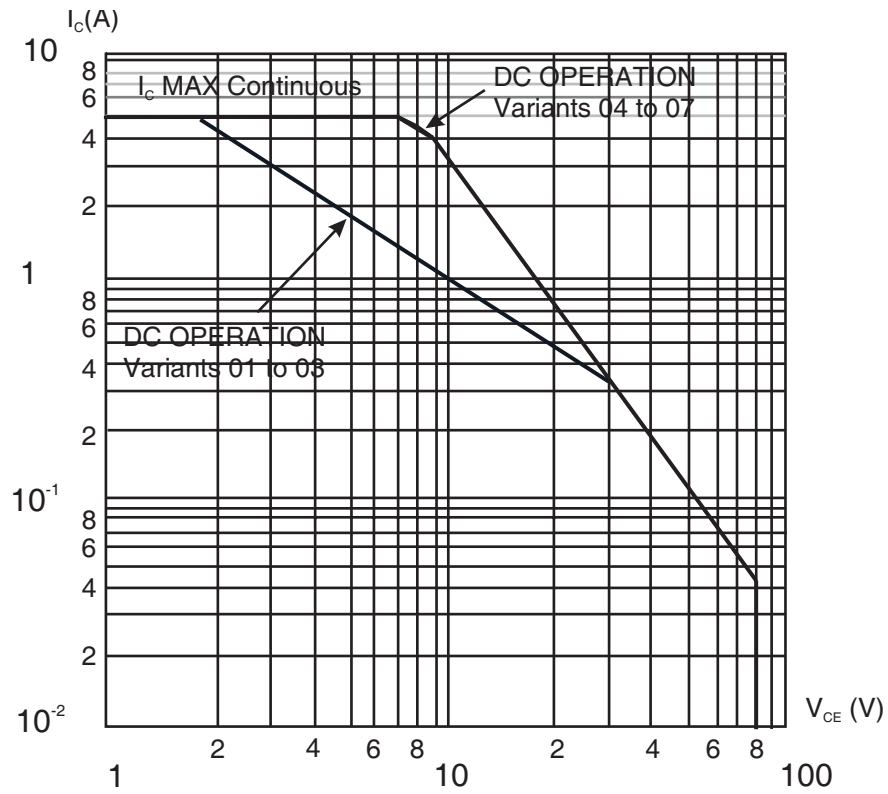
NOTES:

1. For T_{amb} or $T_{case} > +25^{\circ}C$, derate linearly to 0W at +200 $^{\circ}C$.
2. For Variants with tin-lead plating or hot solder dip lead finish all testing, and any handling, performed at $T_{amb} > +125^{\circ}C$ shall be carried out in a 100% inert atmosphere.
3. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
4. Duration 5 seconds maximum and the same package shall not be resoldered until 3 minutes have

elapsed.

5. Safe Operating Area applies as follows:

Maximum Safe Operating Area Graph



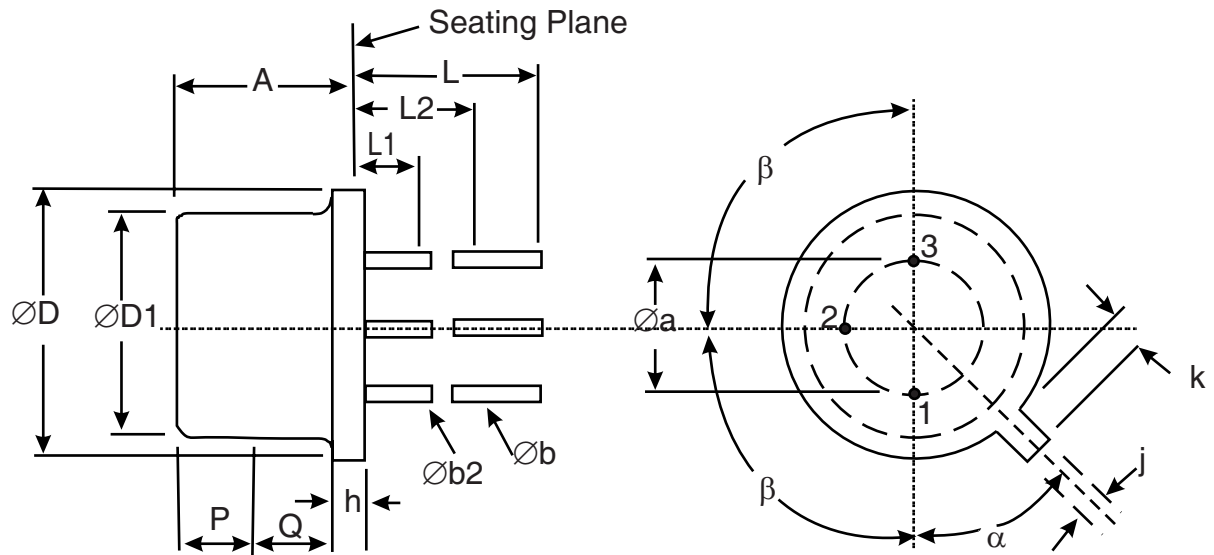
1.6

HANDLING PRECAUTIONS

The TO-257 package contains Beryllium Oxide (BeO) and therefore it must not be ground, machined, sandblasted or subjected to any mechanical operation which will produce dust. The case must not be subjected to any chemical process (e.g. etching) which will produce fumes.

1.7 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

1.7.1 Metal Can Package (TO-39) - 3 lead

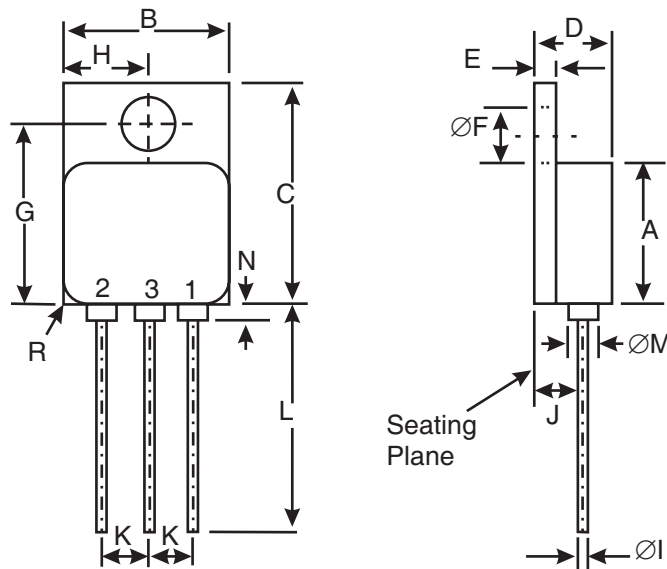


Symbols	Dimensions mm		Notes
	Min	Max	
$\varnothing a$	4.83	5.35	
A	6	6.6	
$\varnothing b$	0.4	0.533	2, 3
$\varnothing b2$	0.4	0.483	2, 3
$\varnothing D$	8.31	9.4	
$\varnothing D1$	7.75	8.51	5
h	0.229	3.18	
j	0.711	0.864	
k	0.737	1.14	4
L	12.7	19	2
L1	-	1.27	2, 3
L2	6.35	-	2, 3
P	2.54	-	5
Q	-	-	6
α	45° BSC		1, 7
β	90° BSC		1

NOTES:

1. Terminal identification is specified by reference to the tab position where Lead 1 = emitter, Lead 2 = base and Lead 3 = collector.
2. Applies to all leads.
3. $\varnothing b2$ applies between L1 and L2. $\varnothing b$ applies between L2 and 12.7mm from the seating plane. Diameter is uncontrolled within L1 and beyond 12.7mm from the seating plane.
4. Measured from the maximum diameter of the actual device.
5. This zone is controlled for automatic handling. The variation in actual diameter within this zone shall not exceed 0.254mm.
6. The details of outline in this zone are optional.
7. Measured from the tab centreline.

1.7.2 Metal Flange Mount Package (TO-257) - 3 lead



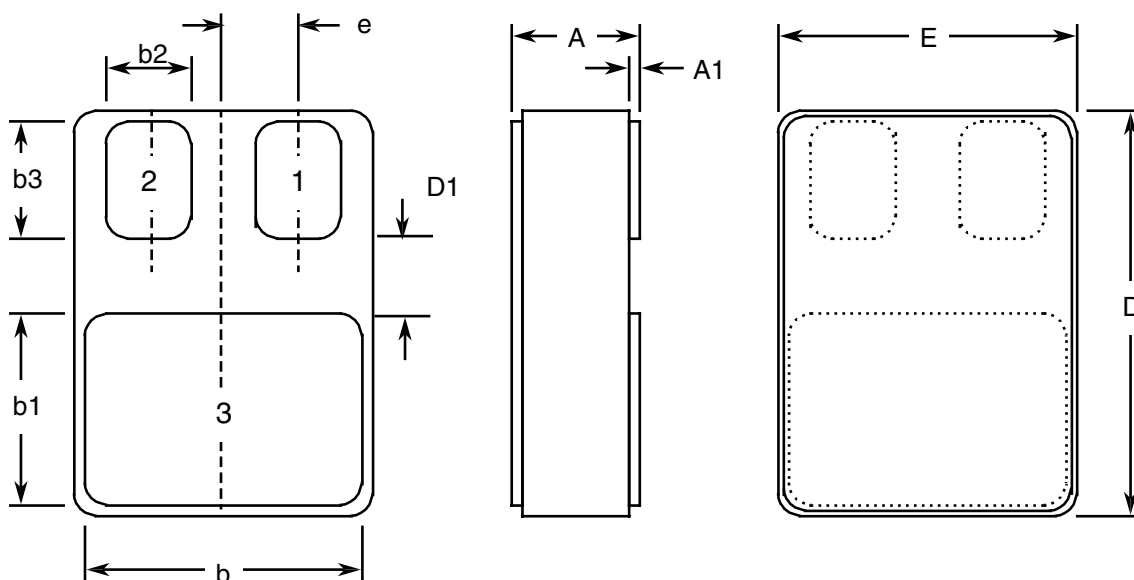
Symbols	Dimensions mm		Notes
	Min	Max	
A	10.41	10.67	
B	10.41	10.67	
C	16.51	16.76	
D	4.7	5.33	
E	0.89	1.14	
$\varnothing F$	3.56	3.81	
G	13.39	13.64	
H	5.13	5.38	
$\varnothing I$	0.64	0.89	2
J	2.92	3.16	
K	2.41	2.67	

Symbols	Dimensions mm		Notes
	Min	Max	
L	15.24	16.51	
ØM	2.29 Typical		2
N	-	0.71	2
R	1.65 Typical		3

NOTES:

1. Terminal identification is specified by the component's geometry where Lead 1 = emitter, Lead 2 = base and Lead 3 = collector.
2. Applies to all leads.
3. Radius of body corner, 4 places.

1.7.3 Surface Mount Package (SMD.5) - 3 terminal



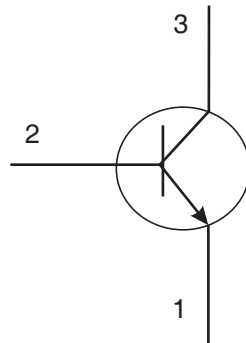
Symbols	Dimensions mm		Notes
	Min	Max	
A	2.84	3.15	
A1	0.25	0.51	
b	7.13	7.39	
b1	5.58	5.84	
b2	2.28	2.54	2
b3	2.92	3.18	2
D	10.03	10.28	
D1	0.76	-	2
E	7.39	7.64	

Symbols	Dimensions mm		Notes
	Min	Max	
e	1.91 BSC		2

NOTES:

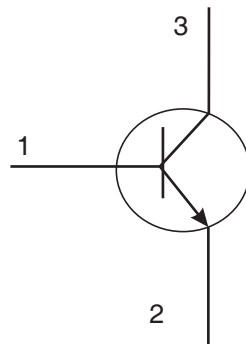
- Terminal identification is specified by the components geometry where Terminal 1 = emitter (base for Variant 07), Terminal 2 = base (emitter for Variant 07) and Terminal 3 = collector.
- 2 places.

1.8 FUNCTIONAL DIAGRAM



Variants 01 to 06

- Emitter.
- Base.
- Collector.



Variant 07

- Base.
- Emitter.
- Collector.

NOTES:

- For TO-39, the collector is internally connected to the case.
- For TO-257, the case is not connected to any lead.
- For SMD.5, the lid is not connected to any terminal.

1.9 MATERIALS AND FINISHES

Materials and finishes shall be as follows:

a) Case

For the metal can package the case shall be hermetically sealed and have a metal body with hard glass seals.

For the metal flange mount package the case shall be hermetically sealed and have a metal body. The leads pass through ceramic eyelets brazed into the frame and the lid shall be welded.

For the surface mount package the case shall be hermetically sealed and have a ceramic body with a Kovar lid.

- b) Leads/Terminals
As specified in Component Type Variants.

2. **REQUIREMENTS**

2.1 **GENERAL**

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 **Deviations from the Generic Specification**

2.1.1.1 Deviation from Screening Tests - Chart F3

High Temperature Reverse Bias Burn-in and the subsequent Final Measurements for HTRB shall be omitted.

2.1.1.2 Deviation from Qualification and Periodic Tests - Chart F4

For SMD.5, Terminal Strength is not applicable.

2.2 **MARKING**

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number.
- (c) Traceability information.
- (d) Warning sign for Beryllium Oxide (TO-257 only)

2.3 **TERMINAL STRENGTH**

The test conditions for terminal strength, tested as specified in the ESCC Generic Specification, shall be as follows:

For TO-39, Test Condition: E, lead fatigue.

For TO-257, Test Condition: A, tension, with an applied force of 10N for a duration of 10s.

2.4 VERIFICATION OF SAFE OPERATING AREA

The Safe Operating Area shall be verified as specified in the ESCC Generic Specification and Maximum Ratings herein. The test conditions shall be:

Test Method = MIL-STD-750, Method 3051, Continuous DC

$T_{case} = +25^{\circ}C$

$V_{CE}=25V$

$I_C=350mA$

Operating Time $\leq 100ms$

2.5 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures.

2.5.1 Room Temperature Electrical Measurements

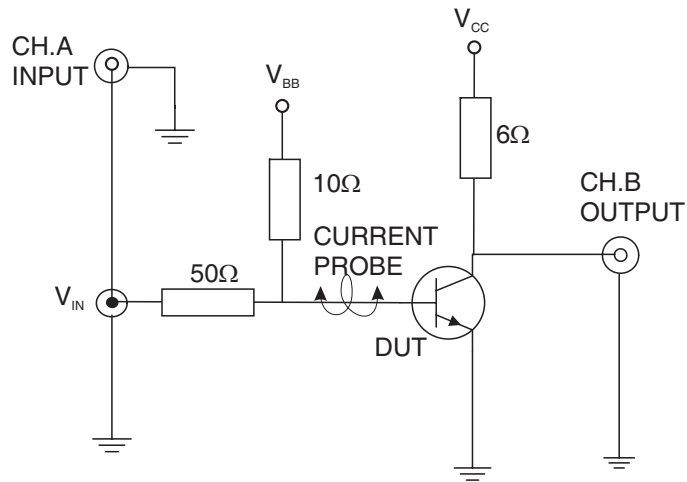
The measurements shall be performed at $T_{amb}=+22 \pm 3^{\circ}C$.

Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions	Limits		Units
				Min	Max	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	3011	$I_C = 100mA$ Bias condition D Note 1	80	-	V
Collector-Emitter Cut-off Current	I_{CES}	3041	$V_{CE} = 60V$ Bias condition C	-	1	μA
	I_{CEO}	3041	$V_{CE} = 40V$ Bias condition D	-	50	μA
Emitter-Base Cut-off Current	I_{EBO1}	3061	$V_{EB}=5V$ Bias condition D	-	1	μA
	I_{EBO2}	3061	$V_{EB} =6V$ Bias condition D	-	1	mA
Forward-Current Transfer Ratio	h_{FE1}	3076	$V_{CE}=5V ; I_C = 50mA$ Note 1	50	-	-
	h_{FE2}	3076	$V_{CE}=5V ; I_C = 2.5A$ Note 1	70	200	-
	h_{FE3}	3076	$V_{CE}=5V ; I_C = 5A$ Note 1	40	-	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)1}$	3071	$I_C=5A$ $I_B=500mA$ Notes 1, 2	-	1.5	V
	$V_{CE(sat)2}$	3071	$I_C=2.5A$ $I_B=250mA$ Notes 1, 2	-	1.45	V

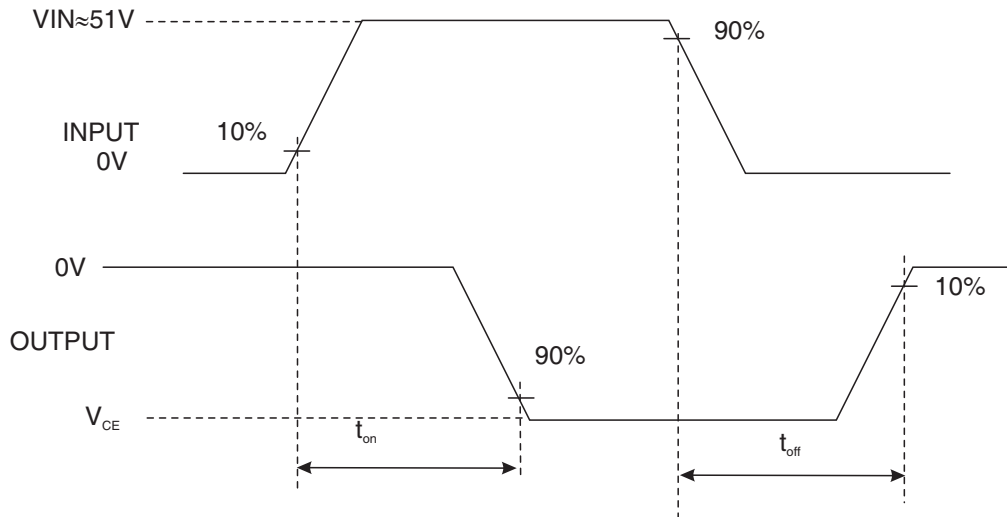
Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions	Limits		Units
				Min	Max	
Base-Emitter Saturation Voltage	$V_{BE(sat)1}$	3066	$I_C=2.5A$ $I_B=250mA$ Test condition A Notes 1, 2	-	1.45	V
	$V_{BE(sat)2}$	3066	$I_C=5A$ $I_B=500mA$ Test condition A Notes 1, 2	-	2.2	V
High Frequency Small Signal Current Gain	h_{fe}	3306	$V_{CE}=5V,$ $I_C=500mA$ $f=20MHz$ Note 3	3.5	-	-
Output Capacitance	C_{obo}	3236	$V_{CB}=10V,$ $I_E=0A$ $f=1MHz$ Note 3	-	250	pF
Turn-on Time	t_{on}	-	$I_C=5A,$ $I_{B1}=500mA$ $I_{B2}=-500mA$ $V_{CC}=30V$ $V_{BB}=-4V$ $V_{IN}\approx 51V$ Notes 3, 4	-	500	ns
Turn-off Time	t_{off}	-	$I_C=5A,$ $I_{B1}=500mA$ $I_{B2}=-500mA$ $V_{CC}=30V$ $V_{BB}=-4V$ $V_{IN}\approx 51V$ Notes 3, 4	-	1.3	μs

NOTES:

1. Pulse measurement: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
2. For TO-39, saturation voltages are measured 6mm from header.
3. For AC characteristics read and record measurements shall be performed on a sample of 32 components with 0 failures allowed. Alternatively a 100% inspection may be performed.
4. t_{on} and t_{off} shall be measured using the following test circuit. The input waveform shall be supplied by a pulse generator with the following characteristics: $t_r \leq 20ns$, Pulse Width = $10\mu s$, Duty Cycle = 1%. The sampling oscilloscope for CH.A and CH.B shall have the characteristics $Z_{IN} \geq 100k\Omega$, $C_{IN} \leq 12pF$ and $t_f \leq 5ns$. Adjustment of V_{IN} shall be made with a suitable current probe to achieve the specified I_{B1} and I_{B2} test conditions, where I_{B1} is the on-state base current and I_{B2} is the post off-state base current.



VOLTAGE WAVEFORMS



2.5.2 High and Low Temperatures Electrical Measurements

Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Collector-Emitter Cut-off Current	I_{CES}	3041	$T_{amb}=+150(+0 -5)^{\circ}C$ $V_{CE} = 60V$ Bias condition C	-	10	μA
Forward-Current Transfer Ratio 2	h_{FE2}	3076	$T_{amb}=-55(+5 -0)^{\circ}C$ $V_{CE}=5V ; I_C = 2.5A$ Note 2	35	-	-

NOTES:

1. Read and record measurements shall be performed on a sample of 5 components with 0 failures

- allowed. Alternatively a 100% inspection may be performed.
- Pulse measurement: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

2.6 **PARAMETER DRIFT VALUES**

Unless otherwise specified, the measurements shall be performed at $T_{\text{amb}} = +22 \pm 3^\circ\text{C}$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Collector-Emitter Cut-off Current	I_{CES}	± 100	-	1000	nA
Forward-Current Transfer Ratio 2	$h_{\text{FE}2}$	$\pm 25\%$	70	200	-
Collector-Emitter Saturation Voltage 1	$V_{\text{CE(sat)1}}$	± 100	-	1500	mV

2.7 **INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS**

Unless otherwise specified, the measurements shall be performed at $T_{\text{amb}} = +22 \pm 3^\circ\text{C}$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Collector-Emitter Cut-off Current	I_{CES}	-	1	μA
Forward-Current Transfer Ratio 2	$h_{\text{FE}2}$	70	200	-
Collector-Emitter Saturation Voltage 1	$V_{\text{CE(sat)1}}$	-	1.5	V

2.8 POWER BURN-IN CONDITIONS

2.8.1 Power Burn-in Conditions (TO-39)

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+20 to +50 (1)	°C
Power Dissipation	P_{tot}	As per Maximum Ratings. Derate P_{tot1} at the chosen T_{amb} using the specified $R_{th(j-a)}$.	W
Collector-Base Voltage	V_{CB}	20	V

NOTES:

1. No heat sink nor forced air directly on the device shall be permitted.

2.8.2 Power Burn-in Conditions (TO-257 and SMD.5)

Characteristics	Symbols	Conditions	Units
Case Temperature	T_{case}	+100 (+0 -5)	°C
Power Dissipation	P_{tot}	As per Maximum Ratings. Derate P_{tot2} at the specified T_{case} using the specified $R_{th(j-c)}$.	W
Collector-Base Voltage	V_{CB}	20	V

2.9 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.

APPENDIX 'A'**AGREED DEVIATIONS FOR STMICROELECTRONICS (F)**

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Deviations from Room Temperature Electrical Measurements	All AC characteristics (Room Temperature Electrical Measurement Note 2) may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes AC characteristic measurements per the Detail Specification. A summary of the pilot lot testing shall be provided if required by the Purchase Order.
Deviations from High and Low Temperatures Electrical Measurements	All characteristics specified may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes characteristic measurements at high and low temperatures per the Detail Specification. A summary of the pilot lot testing shall be provided if required by the Purchase Order.
Deviations from Screening Tests - Chart F3	Solderability is not applicable unless specifically stipulated in the Purchase Order.